## Single Supply Dual Operational Amplifiers

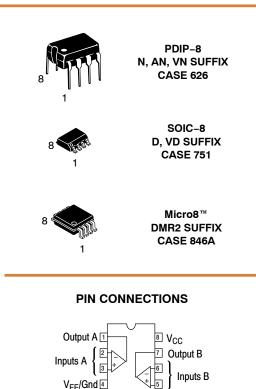
## LM258, LM358, LM358A, LM358E, LM2904, LM2904A, LM2904E, LM2904V, NCV2904

Utilizing the circuit designs perfected for Quad Operational Amplifiers, these dual operational amplifiers feature low power drain, a common mode input voltage range extending to ground/V<sub>EE</sub>, and single supply or split supply operation. The LM358 series is equivalent to one-half of an LM324.

These amplifiers have several distinct advantages over standard operational amplifier types in single supply applications. They can operate at supply voltages as low as 3.0 V or as high as 32 V, with quiescent currents about one–fifth of those associated with the MC1741 (on a per amplifier basis). The common mode input range includes the negative supply, thereby eliminating the necessity for external biasing components in many applications. The output voltage range also includes the negative power supply voltage.

#### Features

- Short Circuit Protected Outputs
- True Differential Input Stage
- Single Supply Operation: 3.0 V to 32 V
- Low Input Bias Currents
- Internally Compensated
- Common Mode Range Extends to Negative Supply
- Single and Split Supply Operation
- ESD Clamps on the Inputs Increase Ruggedness of the Device without Affecting Operation
- NCV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q100 Qualified and PPAP Capable
- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant



#### **ORDERING INFORMATION**

(Top View)

See detailed ordering and shipping information on page 10 of this data sheet.

#### **DEVICE MARKING INFORMATION**

See general marking information in the device marking section on page 11 of this data sheet.





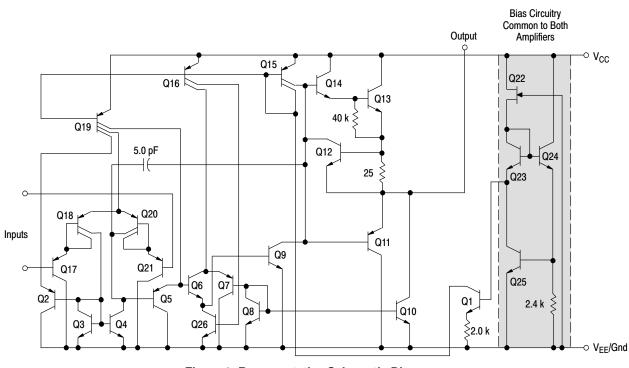


Figure 2. Representative Schematic Diagram (One-Half of Circuit Shown)



| Rating   |   | Symbol   | Value  | Unit |
|--|---|--|--|------|
| Power Supply Voltages<br>Single Supply<br>Split Supplies |   | V <sub>CC</sub><br>V <sub>CC</sub> , V <sub>EE</sub> | 32<br>±16  | Vdc  |
| Input Differential Voltage Range (Note 1)                |   | V <sub>IDR</sub>                                     | ±32  | Vdc  |
| Input Common Mode Voltage Range                          |   | V <sub>ICR</sub>                                     | -0.3 to 32   | Vdc  |
| Output Short Circuit Duration                            |   | t <sub>SC</sub>                                      | Continuous   |      |
| Junction Temperature                                     |   | TJ   | 150  | °C   |
| Thermal Resistance, Junction-to-Air (Note 2)             | Case 846A<br>Case 751<br>Case 626                                     | $R_{	hetaJA}$  | 238<br>212<br>161                                    | °C/W |
| Thermal Resistance, Junction-to-Case                     | Case 751  | $R_{	ext{	heta}JC}$                                  | 72   | °C/W |
| Thermal Resistance, Junction-to-Board                    | Case 751  | $R_{\theta JB}$                                      | 74   | °C/W |
| Storage Temperature Range                                |   | T <sub>stg</sub>                                     | -65 to +150  | ℃    |
| LM2904,  | LM258<br>8, LM358A, LM358E<br>LM2904A, LM2904E<br>/, NCV2904 (Note 3) | T <sub>A</sub>                                       | -25 to +85<br>0 to +70<br>-40 to +105<br>-40 to +125 | °C   |

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. Split Power Supplies.

2. All R<sub>0JA</sub> measurements made on evaluation board with 1 oz. copper traces of minimum pad size. All device outputs were active.

3. NCV2904 is qualified for automotive use.

#### ESD RATINGS

| Rating   | НВМ  | ММ  | Unit |
|--|------|-----|------|
| ESD Protection at any Pin (Human Body Model – HBM, Machine Model – MM) |      |     |      |
| NCV2904 (Note 3)   | 2000 | 200 | V    |
| LM358E, LM2904E  | 2000 | 200 | V    |
| LM358DG/DR2G, LM2904DG/DR2G  | 250  | 100 | V    |
| All Other Devices  | 2000 | 200 | V    |



|  |                            | LM258 LM358, L |            |            | 58, LM3  | 858E       | I          | LM358/    | 4          |            |          |
|--|----------------------------|----------------|------------|------------|----------|------------|------------|-----------|------------|------------|----------|
| Characteristic   | Symbol                     | Min            | Тур        | Max        | Min      | Тур        | Max        | Min       | Тур        | Max        | Unit     |
| Input Offset Voltage $V_{CC}$ = 5.0 V to 30 V, $V_{IC}$ = 0 V to $V_{CC}$ –1.7 V, $V_O \simeq 1.4$ V, $R_S$ = 0 $\Omega$   | V <sub>IO</sub>            |                |            |            |          |            |            |           |            |            | mV       |
| $T_A = 25^{\circ}C$<br>$T_A = T_{high}$ (Note 4)   |                            | -              | 2.0<br>_   | 5.0<br>7.0 | -        | 2.0<br>_   | 7.0<br>9.0 |           | 2.0<br>_   | 3.0<br>5.0 |          |
| $T_A = T_{low}$ (Note 4)   |                            | -              | -          | 7.0        | -        | -          | 9.0        | -         | -          | 5.0        |          |
| Average Temperature Coefficient of Input Offset<br>Voltage<br>$T_A = T_{high}$ to $T_{low}$ (Note 4)   | $\Delta V_{IO} / \Delta T$ | _              | 7.0        | -          | -        | 7.0        | -          | _         | 7.0        | -          | μV/°0    |
| Input Offset Current   | I <sub>IO</sub>            | _              | 3.0        | 30         | _        | 5.0        | 50         | _         | 5.0        | 30         | nA       |
| $T_A = T_{high}$ to $T_{low}$ (Note 4)   | 10                         | -              | _          | 100        | -        | -          | 150        | -         | -          | 75         |          |
| Input Bias Current   | I <sub>IB</sub>            | -              | -45        | -150       | -        | -45        | -250       | -         | -45        | -100       |          |
| $T_A = T_{high}$ to $T_{low}$ (Note 4)   |                            | -              | -50        | -300       | -        | -50        | -500       | -         | -50        | -200       |          |
| Average Temperature Coefficient of Input Offset<br>Current<br>$T_A = T_{high}$ to $T_{low}$ (Note 4)   | $\Delta I_{IO} / \Delta T$ | -              | 10         | -          | -        | 10         | -          | -         | 10         | -          | pA/°     |
| Input Common Mode Voltage Range (Note 5),<br>$V_{CC} = 30 V$   | V <sub>ICR</sub>           | 0              | -          | 28.3       | 0        | -          | 28.3       | 0         | -          | 28.5       | V        |
| $V_{CC} = 30$ V, $T_A = T_{high}$ to $T_{low}$   |                            | 0              | -          | 28         | 0        | -          | 28         | 0         | -          | 28         |          |
| Differential Input Voltage Range   | V <sub>IDR</sub>           | -              | -          | $V_{CC}$   | -        | -          | $V_{CC}$   | -         | -          | $V_{CC}$   | V        |
| Large Signal Open Loop Voltage Gain<br>$R_L = 2.0 \text{ k}\Omega, V_{CC} = 15 \text{ V}, \text{ For Large V}_O \text{ Swing},$<br>$T_A = T_{high} \text{ to } T_{low} \text{ (Note 4)}$ | A <sub>VOL</sub>           | 50<br>25       | 100        | -          | 25<br>15 | 100        | -          | 25<br>15  | 100        | -          | V/m      |
| Channel Separation<br>1.0 kHz $\leq f \leq 20$ kHz, Input Referenced   | CS                         | -              | -120       | _          | -        | -120       | -          | _         | -120       | -          | dB       |
| Common Mode Rejection $R_S \leq 10 \ k\Omega$  | CMR                        | 70             | 85         | _          | 65       | 70         | I          | 65        | 70         | -          | dB       |
| Power Supply Rejection   | PSR                        | 65             | 100        | -          | 65       | 100        | -          | 65        | 100        | -          | dB       |
| Output Voltage–High Limit<br>$T_A = T_{high}$ to $T_{low}$ (Note 4)<br>$V_{CC} = 5.0 \text{ V}, \text{ R}_L = 2.0 \text{ k}\Omega, \text{ T}_A = 25^{\circ}\text{C}$                     | V <sub>OH</sub>            | 3.3            | 3.5        | _          | 3.3      | 3.5        | _          | 3.3       | 3.5        | _          | V        |
| $V_{CC} = 30 \text{ V}, \text{ R}_{L} = 2.0 \text{ k}\Omega$   |                            | 26             | -          | -          | 26       | -          | -          | 26        | -          | -          |          |
| $V_{CC} = 30 \text{ V}, \text{ R}_{L} = 10 \text{ k}\Omega$  | .,                         | 27             | 28         | -          | 27       | 28         | -          | 27        | 28         | -          |          |
| Output Voltage-Low Limit<br>$V_{CC} = 5.0 \text{ V}, \text{ R}_{L} = 10 \text{ k}\Omega,$<br>$T_{A} = T_{high} \text{ to } T_{low} \text{ (Note 4)}$                                     | V <sub>OL</sub>            | -              | 5.0        | 20         | -        | 5.0        | 20         | -         | 5.0        | 20         | mV       |
| Output Source Current<br>$V_{ID} = +1.0 V$ , $V_{CC} = 15 V$<br>$T_A = T_{high}$ to $T_{low}$ (LM358A Only)  | I <sub>O +</sub>           | 20             | 40         | -          | 20       | 40         | -          | 20<br>10  | 40<br>-    | -          | mA       |
| Output Sink Current<br>$V_{ID} = -1.0 V, V_{CC} = 15 V$<br>$T_A = T_{high} \text{ to } T_{low} \text{ (LM358A Only)}$  | I <sub>O –</sub>           | 10             | 20         | -          | 10       | 20         | -          | 10<br>5.0 | 20         | -          | mA<br>mA |
| $V_{\rm ID} = -1.0 \text{ V}, V_{\rm O} = 200 \text{ mV}$  |                            | 12             | 50         | -          | 12       | 50         | -          | 12        | 50         | -          | μΑ       |
| Output Short Circuit to Ground (Note 6)  | I <sub>SC</sub>            | -              | 40         | 60         | -        | 40         | 60         | -         | 40         | 60         | mA       |
| Power Supply Current (Total Device) $T_A = T_{high}$ to $T_{low}$ (Note 4)   | I <sub>CC</sub>            |                |            |            |          |            |            |           |            |            | mA       |
|  |                            | -              | 1.5<br>0.7 | 3.0<br>1.2 | -        | 1.5<br>0.7 | 3.0<br>1.2 | -         | 1.5<br>0.7 | 2.0<br>1.2 |          |

| ELECTRICAL CHARACTERISTICS | $(V_{CC} = 5.0 \text{ V} \text{ V}_{FF} = \text{GND} \text{ T}$ | $\sim -25^{\circ}$ C unless otherwise noted ) |
|----------------------------|---|---|
|                            | $V_{CC} = 3.0 V. V_{FF} = GIND. T$                              | $\Delta = 25$ C. unless otherwise noted.)     |

4. LM258: T<sub>low</sub> = -25°C, T<sub>high</sub> = +85°C LM2904/A/E: T<sub>low</sub> = -40°C, T<sub>high</sub> = +105°C NCV2904 is qualified for automotive use.

LM358, LM358A, LM358E:  $T_{low} = 0^{\circ}C$ ,  $T_{high} = +70^{\circ}C$ LM2904V & NCV2904:  $T_{low} = -40^{\circ}C$ ,  $T_{high} = +125^{\circ}C$ 

The input common mode voltage or either input signal voltage should not be allowed to go negative by more than 0.3 V. The upper end of the common mode voltage range is V<sub>CC</sub> – 1.7 V, but either or both inputs can go to +32 V without damage, independent of the magnitude

of  $V_{CC}$ . 6. Short circuits from the output to  $V_{CC}$  can cause excessive heating and eventual destruction. Destructive dissipation can result from



|  |                            | LM2904/LM2904E |            |                 | L   | M2904      | Α               | LM29 | 04V, NC    | V2904           |      |
|--|----------------------------|----------------|------------|-----------------|-----|------------|-----------------|------|------------|-----------------|------|
| Characteristic   | Symbol                     | Min            | Тур        | Max             | Min | Тур        | Max             | Min  | Тур        | Max             | Unit |
| Input Offset Voltage V <sub>CC</sub> = 5.0 V to 30 V, V <sub>IC</sub> = 0 V to V <sub>CC</sub> –1.7 V, V <sub>O</sub> $\approx$ 1.4 V, R <sub>S</sub> = 0 $\Omega$ | V <sub>IO</sub>            |                |            |                 |     |            |                 |      |            |                 | mV   |
| $T_A = 25^{\circ}C$  |                            | -              | 2.0        | 7.0             | -   | 2.0        | 7.0             | -    | -          | 7.0             |      |
| T <sub>A</sub> = T <sub>high</sub> (Note 7)  |                            | -              | -          | 10              | -   | -          | 10              | -    | -          | 13              |      |
| $T_A = T_{low}$ (Note 7)   |                            | -              | -          | 10              | -   | -          | 10              | -    | -          | 10              |      |
| Average Temperature Coefficient of Input Offset<br>Voltage   | $\Delta V_{IO} / \Delta T$ | -              | 7.0        | -               | -   | 7.0        | -               | -    | 7.0        | -               | μV/° |
| $T_A = T_{high}$ to $T_{low}$ (Note 7)   |                            |                |            |                 |     |            |                 |      |            |                 |      |
| Input Offset Current   | I <sub>IO</sub>            | -              | 5.0        | 50              | -   | 5.0        | 50              | -    | 5.0        | 50              | nA   |
| $T_A = T_{high}$ to $T_{low}$ (Note 7)   |                            | -              | 45         | 200             | -   | 45         | 200             | -    | 45         | 200             |      |
| Input Bias Current   | IIB                        | -              | -45<br>-50 | -250<br>-500    | _   | -45<br>-50 | -100<br>-250    | -    | -45<br>-50 | -250<br>-500    |      |
| $T_A = T_{high}$ to $T_{low}$ (Note 7)   |                            | _              |            |                 |     |            |                 |      |            |                 | • 10 |
| Average Temperature Coefficient of Input Offset<br>Current   | $\Delta I_{IO} / \Delta T$ | -              | 10         | -               | -   | 10         | _               | _    | 10         | -               | pA/° |
| $T_A = T_{high}$ to $T_{low}$ (Note 7)   |                            |                |            |                 |     |            |                 |      |            |                 |      |
| Input Common Mode Voltage Range (Note 8),<br>V <sub>CC</sub> = 30 V  | V <sub>ICR</sub>           | 0              | -          | 28.3            | 0   | -          | 28.3            | 0    | -          | 28.3            | V    |
| $V_{CC}$ = 30 V, $T_A$ = $T_{high}$ to $T_{low}$   |                            | 0              | -          | 28              | 0   | -          | 28              | 0    | -          | 28              |      |
| Differential Input Voltage Range   | V <sub>IDR</sub>           | -              | -          | V <sub>CC</sub> | -   | -          | V <sub>CC</sub> | -    | -          | V <sub>CC</sub> | V    |
| Large Signal Open Loop Voltage Gain  | A <sub>VOL</sub>           |                |            |                 |     |            |                 |      |            |                 | V/m  |
| $R_L$ = 2.0 k $\Omega$ , $V_{CC}$ = 15 V, For Large $V_O$ Swing,   |                            | 25             | 100        | -               | 25  | 100        | -               | 25   | 100        | -               |      |
| $T_A = T_{high}$ to $T_{low}$ (Note 7)   |                            | 15             | -          | -               | 15  | -          | -               | 15   | -          | -               |      |
| Channel Separation   | CS                         | -              | -120       | -               | -   | -120       | -               | -    | -120       | -               | dB   |
| 1.0 kHz $\leq$ f $\leq$ 20 kHz, Input Referenced   |                            |                |            |                 |     |            |                 |      |            |                 |      |
| $\begin{array}{l} \mbox{Common Mode Rejection} \\ \mbox{R}_S \leq 10 \ \mbox{k} \Omega \end{array}$  | CMR                        | 50             | 70         | -               | 50  | 70         | -               | 50   | 70         | -               | dB   |
| Power Supply Rejection   | PSR                        | 50             | 100        | -               | 50  | 100        | -               | 50   | 100        | -               | dB   |
| Output Voltage–High Limit<br>$T_A = T_{high}$ to $T_{low}$ (Note 7)  | V <sub>OH</sub>            |                |            |                 |     |            |                 |      |            |                 | V    |
| V <sub>CC</sub> = 5.0 V, R <sub>L</sub> = 2.0 kΩ, T <sub>A</sub> = 25°C  |                            | 3.3            | 3.5        | -               | 3.3 | 3.5        | -               | 3.3  | 3.5        | -               |      |
| $V_{CC}$ = 30 V, $R_L$ = 2.0 k $\Omega$  |                            | 26             | -          | -               | 26  | -          | -               | 26   | -          | -               |      |
| $V_{CC}$ = 30 V, $R_L$ = 10 k $\Omega$   |                            | 27             | 28         | -               | 27  | 28         | -               | 27   | 28         | -               |      |
| Output Voltage–Low Limit $V_{CC}$ = 5.0 V, $R_L$ = 10 k $\Omega$ , $T_A$ = T <sub>high</sub> to T <sub>low</sub> (Note 7)  | V <sub>OL</sub>            | -              | 5.0        | 20              | -   | 5.0        | 20              | -    | 5.0        | 20              | mV   |
| Output Source Current  |                            | 20             | 40         | _               | 20  | 40         | _               | 20   | 40         | _               | mA   |
| V <sub>ID</sub> = +1.0 V, V <sub>CC</sub> = 15 V   | I <sub>O+</sub>            | 20             | 40         | _               | 20  | 40         | _               | 20   | 40         | _               | - MA |
| Output Sink Current  | I <sub>O –</sub>           |                |            |                 |     |            |                 |      |            |                 |      |
| $V_{ID} = -1.0 \text{ V}, V_{CC} = 15 \text{ V}$   |                            | 10             | 20         | -               | 10  | 20         | -               | 10   | 20         | -               | mA   |
| $V_{ID} = -1.0 \text{ V}, \text{ V}_{O} = 200 \text{ mV}$  |                            | -              | -          | -               | -   | -          | -               | -    | -          | -               | μA   |
| Output Short Circuit to Ground (Note 9)  | I <sub>SC</sub>            | -              | 40         | 60              | -   | 40         | 60              | -    | 40         | 60              | mA   |
| Power Supply Current (Total Device)<br>$T_A = T_{high}$ to $T_{low}$ (Note 7)  | Icc                        |                |            |                 |     |            |                 |      |            |                 | mA   |
| $V_{CC} = 30 \text{ V}, \text{ V}_{O} = 0 \text{ V}, \text{ R}_{L} = \infty$   |                            | -              | 1.5        | 3.0             | -   | 1.5        | 3.0             | -    | 1.5        | 3.0             |      |
| $V_{CC} = 5 V, V_{O} = 0 V, R_{L} = \infty$  |                            | _              | 0.7        | 1.2             | _   | 0.7        | 1.2             | - 1  | 0.7        | 1.2             |      |

| ELECTRICAL CHARACTERISTICS (V <sub>CC</sub> = 5.0 V, V <sub>EE</sub> = Gnd, T <sub>A</sub> = 25°C, unless otherwise noted.) |
|---|
|---|

7. LM258: T<sub>Iow</sub> = -25°C, T<sub>high</sub> = +85°C LM2904/A/E: T<sub>Iow</sub> = -40°C, T<sub>high</sub> = +105°C *NCV2904 is qualified for automotive use.*  LM358, LM358A, LM358E:  $T_{low} = 0^{\circ}C$ ,  $T_{high} = +70^{\circ}C$ LM2904V & NCV2904:  $T_{low} = -40^{\circ}C$ ,  $T_{high} = +125^{\circ}C$ 

 The input common mode voltage or either input signal voltage should not be allowed to go negative by more than 0.3 V. The upper end of the common mode voltage range is V<sub>CC</sub> – 1.7 V, but either or both inputs can go to +32 V without damage, independent of the magnitude of V<sub>CC</sub>.

 Short circuits from the output to V<sub>CC</sub> can cause excessive heating and eventual destruction. Destructive dissipation can result from simultaneous shorts on all amplifiers.

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.



### **CIRCUIT DESCRIPTION**

The LM358 series is made using two internally compensated, two-stage operational amplifiers. The first stage of each consists of differential input devices Q20 and Q18 with input buffer transistors Q21 and Q17 and the differential to single ended converter Q3 and Q4. The first stage performs not only the first stage gain function but also performs the level shifting and transconductance reduction functions. By reducing the transconductance, a smaller compensation capacitor (only 5.0 pF) can be employed, thus saving chip area. The transconductance reduction is accomplished by splitting the collectors of Q20 and Q18. Another feature of this input stage is that the input common mode range can include the negative supply or ground, in single supply operation, without saturating either the input devices or the differential to single-ended converter. The second stage consists of a standard current source load amplifier stage.

Each amplifier is biased from an internal-voltage regulator which has a low temperature coefficient thus giving each amplifier good temperature characteristics as well as excellent power supply rejection.

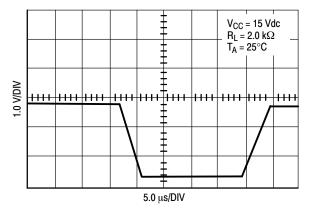
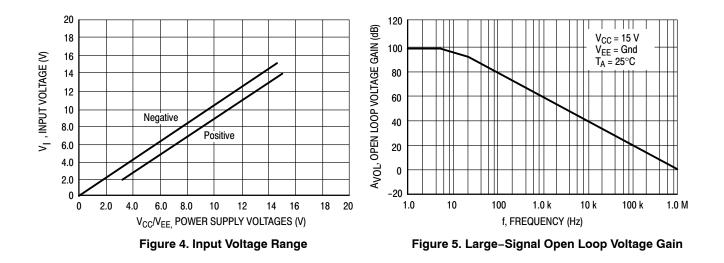


Figure 3. Large Signal Voltage Follower Response





LM258, LM358, LM358A, LM358E, LM2904, LM2904A, LM2904E, LM2904V, NCV2904

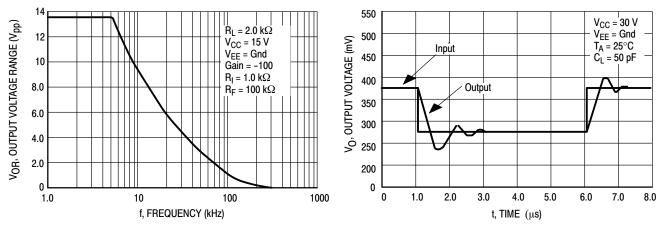


Figure 6. Large–Signal Frequency Response

Figure 7. Small Signal Voltage Follower Pulse Response (Noninverting)

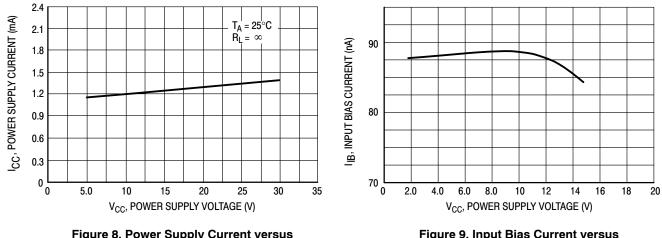


Figure 8. Power Supply Current versus Power Supply Voltage

Figure 9. Input Bias Current versus Supply Voltage



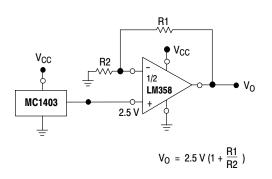


Figure 10. Voltage Reference

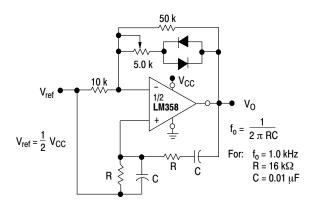


Figure 11. Wien Bridge Oscillator

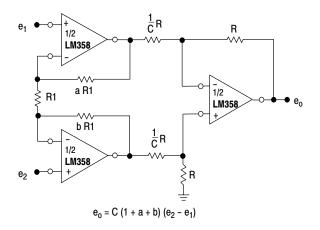
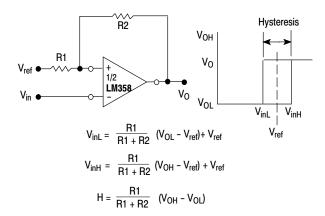


Figure 12. High Impedance Differential Amplifier





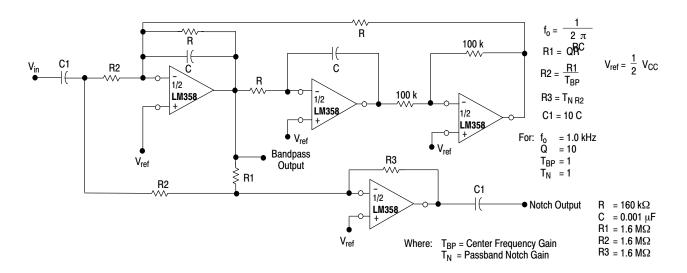
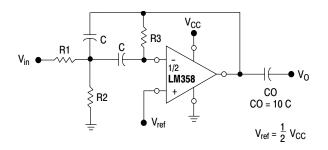


Figure 14. Bi-Quad Filter





Given:  $f_0$  = center frequency A(f\_0) = gain at center frequency

Choose value  $f_0, C$ 

Then: R3 = 
$$\frac{Q}{\pi f_0 C}$$
  
R1 =  $\frac{R3}{2 A(f_0)}$   
R2 =  $\frac{R1 R3}{4Q^2 R1 - R3}$ 

For less than 10% error from operational amplifier.  $\frac{Q_0 f_0}{BW} < 0.1$ 

Where fo and BW are expressed in Hz.

If source impedance varies, filter may be preceded with voltage follower buffer to stabilize filter parameters.

Figure 16. Multiple Feedback Bandpass Filter

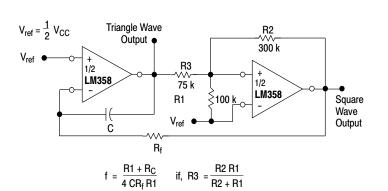


Figure 15. Function Generator



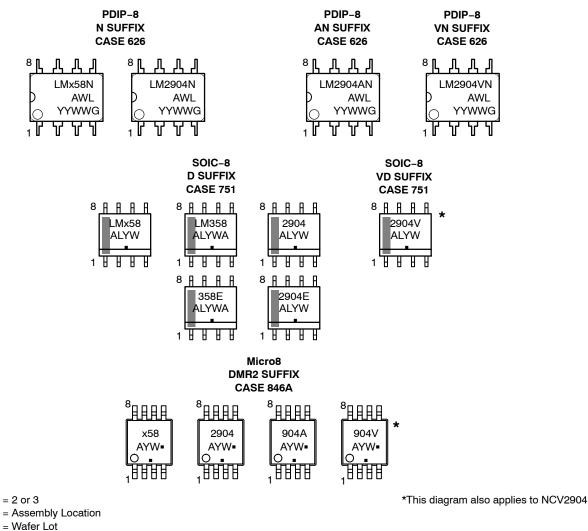
#### ORDERING INFORMATION

| Device        | Operating Temperature Range | Package             | Shipping <sup>†</sup> |
|---------------|-----------------------------|---------------------|-----------------------|
| LM358ADR2G    |                             |                     | 2500 / Tape & Reel    |
| LM358DG       |                             | SOIC-8<br>(Pb-Free) | 98 Units / Rail       |
| LM358DR2G     |                             | (1.5.1100)          | 2500 / Tape & Reel    |
| LM358EDR2G    | 0°C to +70°C                | SOIC-8<br>(Pb-Free) | 2500 / Tape & Reel    |
| LM358DMR2G    |                             | Micro8<br>(Pb–Free) | 4000 / Tape & Reel    |
| LM358NG       |                             | PDIP-8<br>(Pb-Free) | 50 Units / Rail       |
| LM258DG       |                             | SOIC-8              | 98 Units / Rail       |
| LM258DR2G     |                             | (Pb-Free)           | 2500 / Tape & Reel    |
| LM258DMR2G    | −25°C to +85°C              | Micro8<br>(Pb–Free) | 4000 / Tape & Reel    |
| LM258NG       |                             | PDIP-8<br>(Pb-Free) | 50 Units / Rail       |
| LM2904DG      |                             | SOIC-8<br>(Pb-Free) | 98 Units / Rail       |
| LM2904DR2G    |                             |                     | 2500 / Tape & Reel    |
| LM2904EDR2G   |                             | SOIC-8<br>(Pb-Free) | 2500 / Tape & Reel    |
| LM2904DMR2G   |                             | Micro8<br>(Pb–Free) | 2500 / Tape & Reel    |
| LM2904NG      | −40°C to +105°C             | PDIP-8<br>(Pb-Free) | 50 Units / Rail       |
| LM2904ADMG    |                             | Micro8              | 4000 / Tape & Reel    |
| LM2904ADMR2G  |                             | (Pb-Free)           | 4000 / Tape & Reel    |
| LM2904ANG     |                             | PDIP-8<br>(Pb-Free) | 50 Units / Rail       |
| LM2904VDG     |                             | SOIC-8              | 98 Units / Rail       |
| LM2904VDR2G   |                             | (Pb-Free)           | 2500 / Tape & Reel    |
| LM2904VDMR2G  |                             | Micro8<br>(Pb–Free) | 4000 / Tape & Reel    |
| LM2904VNG     | −40°C to +125°C             | PDIP-8<br>(Pb-Free) | 50 Units / Rail       |
| NCV2904DR2G*  |                             | SOIC-8<br>(Pb-Free) | 2500 / Tape & Reel    |
| NCV2904DMR2G* |                             | Micro8<br>(Pb–Free) | 4000 / Tape & Reel    |

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

\*NCV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q100 Qualified and PPAP Capable.





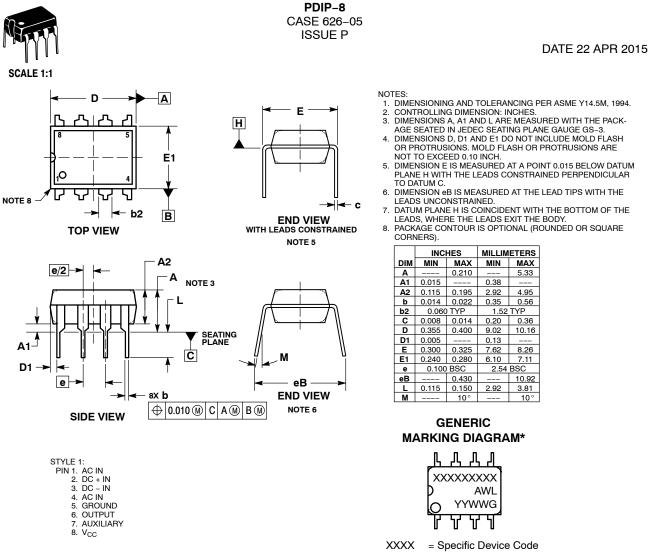
#### **MARKING DIAGRAMS**

- х
- А
- WL, L
- YY, Y = Year

- WW, W = Work Week
- = Pb-Free Package G
  - = Pb-Free Package (Note: Microdot may be in either location)



# onsemi



A = Assembly Location

- WL = Wafer Lot
- YY = Year
- WW = Work Week
- G = Pb-Free Package

\*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "•", may or may not be present. Some products may not follow the Generic Marking.

| DOCUMENT NUMBER:         98ASB42420B         Electronic versions are uncontrolled except when accessed directly from the Document Repository.           Printed versions are uncontrolled except when stamped "CONTROLLED COPY" in red.  |  |  |  |  |  |  |  |
|--|--|--|--|--|--|--|--|
| DESCRIPTION: PDIP-8 PAGE 1 OF 1  |  |  |  |  |  |  |  |
| onsemi and ONSEMi are trademarks of Semiconductor Components Industries, LLC dba onsemi or its subsidiaries in the United States and/or other countries. onsemi reserves the right to make changes without further notice to any products herein. onsemi makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does onsemi assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. onsemi does not convey any license under its patent rights or other is. |  |  |  |  |  |  |  |

# onsemi



\*For additional information on our Pb-Free strategy and soldering details, please download the **onsemi** Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

#### STYLES ON PAGE 2

| DOCUMENT NUMBER:  | ENT NUMBER: 98ASB42564B Electronic versions are uncontrolled except when accessed directly from the Document Reposito<br>Printed versions are uncontrolled except when stamped "CONTROLLED COPY" in red. |  |             |  |  |  |  |  |
|---|--|--|-------------|--|--|--|--|--|
| DESCRIPTION:  | SOIC-8 NB  |  | PAGE 1 OF 2 |  |  |  |  |  |
|   |  |  |             |  |  |  |  |  |
| onsemi and ONSEMi. are trademarks of Semiconductor Components Industries, LLC dba onsemi or its subsidiaries in the United States and/or other countries. onsemi reserves<br>the right to make changes without further notice to any products herein. onsemi makes no warranty, representation or guarantee regarding the suitability of its products for any particular<br>purpose, nor does onsemi assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation<br>special, consequential or incidental damages. onsemi does not convey any license under its patent rights nor the rights of others. |  |  |             |  |  |  |  |  |

#### SOIC-8 NB CASE 751-07 ISSUE AK

STYLE 1: PIN 1. EMITTER COLLECTOR 2. COLLECTOR 3. 4. EMITTER 5. EMITTER BASE 6. 7 BASE EMITTER 8. STYLE 5: PIN 1. DRAIN 2. DRAIN З. DRAIN DRAIN 4. GATE 5. 6. GATE SOURCE 7. 8. SOURCE STYLE 9: PIN 1. EMITTER, COMMON COLLECTOR, DIE #1 COLLECTOR, DIE #2 2. З. EMITTER, COMMON 4. 5. EMITTER, COMMON 6 BASE. DIE #2 BASE, DIE #1 7. 8. EMITTER, COMMON STYLE 13: PIN 1. N.C. 2. SOURCE 3 GATE 4. 5. DRAIN 6. DRAIN DRAIN 7. 8. DRAIN STYLE 17: PIN 1. VCC 2. V2OUT V10UT З. TXE 4. 5. RXE 6. VFF 7. GND 8. ACC STYLE 21: PIN 1. CATHODE 1 2. CATHODE 2 3 CATHODE 3 CATHODE 4 4. 5. CATHODE 5 6. COMMON ANODE COMMON ANODE 7. 8. CATHODE 6 STYLE 25: PIN 1. VIN 2 N/C REXT З. 4. GND 5. IOUT 6. IOUT IOUT 7. 8. IOUT STYLE 29: BASE, DIE #1 PIN 1. 2 EMITTER, #1 BASE, #2 З. EMITTER, #2 4. 5 COLLECTOR, #2 COLLECTOR, #2 6.

STYLE 2: PIN 1. COLLECTOR, DIE, #1 2. COLLECTOR, #1 COLLECTOR, #2 3. 4 COLLECTOR, #2 BASE, #2 5. EMITTER, #2 6. 7 BASE #1 EMITTER, #1 8. STYLE 6: PIN 1. SOURCE 2. DRAIN 3. DRAIN SOURCE 4. SOURCE 5. 6. GATE GATE 7. 8. SOURCE STYLE 10: GROUND PIN 1. BIAS 1 OUTPUT 2. З. GROUND 4. 5. GROUND 6 BIAS 2 INPUT 7. 8. GROUND STYLE 14: PIN 1. N-SOURCE 2. N-GATE 3 P-SOURCE P-GATE 4. P-DRAIN 5 6. P-DRAIN N-DRAIN 7. N-DRAIN 8. STYLE 18: PIN 1. ANODE ANODE 2. SOURCE 3. GATE 4. 5. DRAIN 6 DRAIN CATHODE 7. 8. CATHODE STYLE 22: PIN 1. I/O LINE 1 2. COMMON CATHODE/VCC 3 COMMON CATHODE/VCC 4. I/O LINE 3 COMMON ANODE/GND 5. 6. I/O LINE 4 7. I/O LINE 5 8. COMMON ANODE/GND STYLE 26: PIN 1. GND 2 dv/dt З. ENABLE 4. ILIMIT 5. SOURCE SOURCE 6. SOURCE 7. 8. VCC STYLE 30: DRAIN 1 PIN 1. DRAIN 1 2 GATE 2 З. SOURCE 2 4. SOURCE 1/DRAIN 2 SOURCE 1/DRAIN 2 5. 6.

STYLE 3: PIN 1. DRAIN, DIE #1 DRAIN, #1 2. DRAIN, #2 З. DRAIN, #2 4. GATE, #2 5. SOURCE, #2 6. 7 GATE #1 8. SOURCE, #1 STYLE 7: PIN 1. INPUT 2. EXTERNAL BYPASS THIRD STAGE SOURCE GROUND З. 4. 5. DRAIN 6. GATE 3 SECOND STAGE Vd 7. FIRST STAGE Vd 8. STYLE 11: PIN 1. SOURCE 1 GATE 1 SOURCE 2 2. 3. GATE 2 4. 5. DRAIN 2 6. DRAIN 2 DRAIN 1 7. 8. DRAIN 1 STYLE 15: PIN 1. ANODE 1 2. ANODE 1 ANODE 1 3 ANODE 1 4. 5. CATHODE, COMMON CATHODE, COMMON CATHODE, COMMON 6. 7. CATHODE, COMMON 8. STYLE 19: PIN 1. SOURCE 1 GATE 1 SOURCE 2 2. 3. GATE 2 4. 5. DRAIN 2 6. MIRROR 2 7. DRAIN 1 8. **MIRROR 1** STYLE 23: PIN 1. LINE 1 IN COMMON ANODE/GND COMMON ANODE/GND 2. 3 LINE 2 IN 4. LINE 2 OUT 5. COMMON ANODE/GND COMMON ANODE/GND 6. 7. 8. LINE 1 OUT STYLE 27: PIN 1. ILIMIT 2 OVI 0 UVLO З. 4. INPUT+ 5. 6. SOURCE SOURCE SOURCE 7. 8 DRAIN

#### STYLE 4: PIN 1. 2. ANODE ANODE ANODE З. 4. ANODE ANODE 5. 6. ANODE 7 ANODE COMMON CATHODE 8. STYLE 8: PIN 1. COLLECTOR, DIE #1 2. BASE, #1 BASE #2 З. COLLECTOR, #2 4. COLLECTOR, #2 5. 6. EMITTER, #2 EMITTER, #1 7. 8. COLLECTOR, #1 STYLE 12: PIN 1. SOURCE SOURCE 2. 3. GATE 4. 5. DRAIN 6. DRAIN DRAIN 7. 8. DRAIN STYLE 16 EMITTER, DIE #1 PIN 1. 2. BASE, DIE #1 EMITTER, DIE #2 3 BASE, DIE #2 4. 5. COLLECTOR, DIE #2 6. COLLECTOR, DIE #2 COLLECTOR, DIE #1 7. COLLECTOR, DIE #1 8. STYLE 20: PIN 1. SOURCE (N) GATE (N) SOURCE (P) 2. 3. 4. GATE (P) 5. DRAIN 6. DRAIN DRAIN 7. 8. DRAIN STYLE 24: PIN 1. BASE EMITTER 2. 3 COLLECTOR/ANODE COLLECTOR/ANODE 4. 5. CATHODE

6. CATHODE COLLECTOR/ANODE 7. 8. COLLECTOR/ANODE STYLE 28: PIN 1. SW\_TO\_GND 2. DASIC OFF DASIC\_SW\_DET З. 4. GND 5. 6. V MON VBULK 7. VBULK

7. VOULK 8. VIN

| DOCUMENT NUMBER: | 98ASB42564B | Electronic versions are uncontrolled except when accessed directly from<br>Printed versions are uncontrolled except when stamped "CONTROLLED |             |
|------------------|-------------|--|-------------|
| DESCRIPTION:     | SOIC-8 NB   |  | PAGE 2 OF 2 |
|                  |             |  |             |

SOURCE 1/DRAIN 2

7.

8. GATE 1

onsemi and ONSEMI are trademarks of Semiconductor Components Industries, LLC dba onsemi or its subsidiaries in the United States and/or other countries. onsemi reserves the right to make changes without further notice to any products herein. onsemi makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does onsemi assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. onsemi does not convey any license under its patent rights or others.

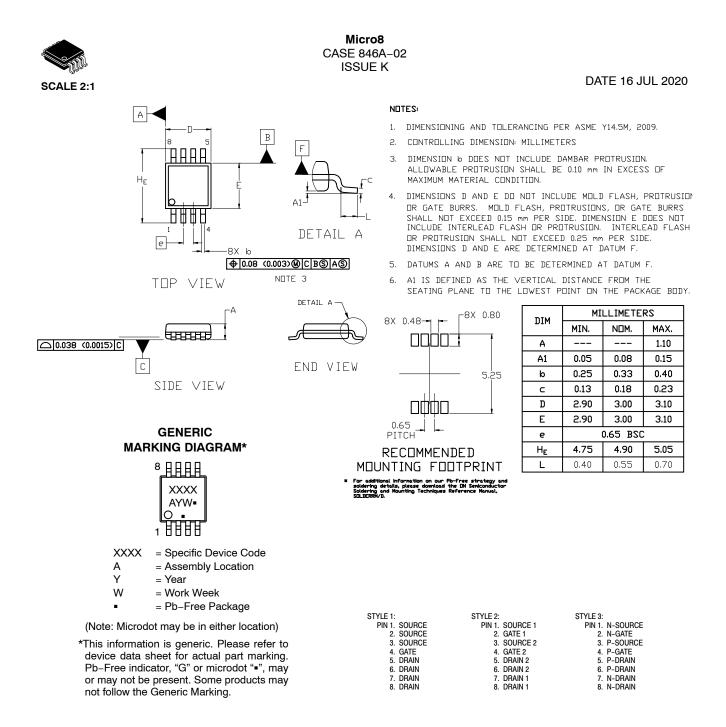
7.

8

COLLECTOR, #1

COLLECTOR, #1

# onsemi



 
 DOCUMENT NUMBER:
 98ASB14087C
 Electronic versions are uncontrolled except when accessed directly from the Document Repository. Printed versions are uncontrolled except when stamped "CONTROLLED COPY" in red.

 DESCRIPTION:
 MICRO8
 PAGE 1 OF 1

 onsemi and ONSEMi are trademarks of Semiconductor Components Industries, LLC dba onsemi or its subsidiaries in the United States and/or other countries. onsemi reserves the right to make changes without further notice to any products herein. onsemi makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does onsemi assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation

special, consequential or incidental damages. onsemi does not convey any license under its patent rights nor the rights of others.

© Semiconductor Components Industries, LLC, 2019

onsemi, ONSEMI, and other names, marks, and brands are registered and/or common law trademarks of Semiconductor Components Industries, LLC dba "onsemi" or its affiliates and/or subsidiaries in the United States and/or other countries. onsemi owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of onsemi's product/patent coverage may be accessed at <u>www.onsemi.com/site/pdf/Patent\_Marking.pdf</u>. onsemi reserves the right to make changes at any time to any products or information herein, without notice. The information herein is provided "as-is" and onsemi makes no warranty, representation or guarantee regarding the accuracy of the information, product features, availability, functionality, or suitability of its products for any particular purpose, nor does onsemi assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or indental damages. Buyer is responsible for its products and applications using onsemi products, including compliance with all laws, regulations and safety requirements or standards, regardless of any support or applications information provided by onsemi. "Typical" parameters which may be provided in onsemi data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. onsemi does not convey any license under any of its intellectual property rights nor the rights of others. onsemi products are not designed, intended, or authorized for use as a critical component in life support systems or any FDA Class 3 medical devices or medical devices with a same or similar classification. Buyer shall indemnify and hold onsemi and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs,

#### ADDITIONAL INFORMATION

TECHNICAL PUBLICATIONS:

Technical Library: www.onsemi.com/design/resources/technical-documentation onsemi Website: www.onsemi.com

ONLINE SUPPORT: <u>www.onsemi.com/support</u> For additional information, please contact your local Sales Representative at <u>www.onsemi.com/support/sales</u>

## **Mouser Electronics**

Authorized Distributor

Click to View Pricing, Inventory, Delivery & Lifecycle Information:

ON Semiconductor:

LM258N LM2904N LM358N